Silicon Switching Diode



Rev. V3

Features

- Available in JAN, JANTX, and JANTXV per MIL-PRF-19500/116
- Metallurgically Bonded
- Hermetically Sealed
- Double Plug Construction

Maximum Ratings



Operating & Storage Temperature: -65° C to $+175^{\circ}$ C Operating Current: 200 mA @ T_A = $+25^{\circ}$ C Derating Factor: 1.14 mA/°C above T_A = $+25^{\circ}$ C Surge Current A: 2.00 A, sinewave, Pw = 8.3 ms

	-			•		•			•	•		
JEDEC TYPE#	V _{BR} @ 100 μΑ	V _{RWM}	I _O (PCB) TA = +75 C (1)	V _{F1} I _F = 10 mA	V _{F2} I _F = 100* mA	T _{rr} ¹	I _{R1} @ 20 Vdc	I _{R2} @ 75 Vdc	I _{R3} @ 20 Vdc T _A =150°C	I _{R4} @ 75 Vdc T _A =150°C	Capacitance @ 0 V	Capacitance @1.5 V
	Volts	Volts (pk)	mA	Vdc	Vdc	nsec	nA	nA	μA	μA	pF	pF
1N914	100	75	200	0.8	1.2	5	25	500	35	75	4.0	2.8
1N4148-1	100	75	200	0.8	1.2	5	35	500	35	75	4.0	2.8
1N4531	100	75	200	0.8	1.2	5	35	500	35	75	4.0	2.8

Electrical Specifications @ $T_A = +25^{\circ}C$ (unless otherwise specified)

1. $I_F = I_R = 10 \text{ mA}, R_L = 100 \text{ ohms}.$

* For 1N914 V_{F2} is measured at I_F = 50 mA dc

Thermal Characteristics

Parameter	Absolute Maximum
$R_{\text{eJL}}^{\left(2\right)}$ (L = .375 inch)	250°C/W
R _{@JA(PCB)} ⁽²⁾ ⁽³⁾	325°C/W

(2) See figures 11, 12, and 13 of MIL-PRF-19500/116 for thermal impedance curves.

(3) T_A = +75°C for axial leaded devices on printed circuit board. PCB = FR4 - .0625 inch (1.59 mm) 1 layer,1 oz Cu, horizontal, in still air; pads for axial device = .092 inch (2.34mm) diameter, strip = 0.30 inch (0.76 mm) x 1 inch (25.4 mm) long, lead length L ≤ 0.187 inch (≤ 4.75 mm); R_{NJA} with a defined PCB thermal resistance condition included, is measured at I₀ = 200 mA dc.

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Graphs



1. This is the true inverse of the worst case thermal resistance value. All devices are capable of operating at $\leq T_J$ specified on this curve. Any parallel line to this curve will intersect the appropriate current for the desired maximum T allowed.

- 2. Derate design curve constrained by the maximum junction temperature (T $_J$ \leq +175°C) and current rating
- specified. (See 1.3.) 3. Derate design curve chosen at $T_J \leq +150^{\circ}$ C, where the maximum temperature of electrical test is performed. 4. Derate design curves chosen at T_J \leq +125°C, and 110°C to show current rating where most users want to limit T_J in their application.



 $R_{\theta JL} = 250^{\circ}C/W$

NOTE: $Z_{\theta JX}$ = 70°C/W maximum at t_H = 10 ms.

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Outline Drawing (DO-35, DO-34)



	Dimensions								
Types	1.te	Inc	hes	Millimeters					
	Ltr	Min	Max	Min	Max				
1N4148-1	BD	.056	.075	1.42	1.91				
1N914	BL	.140	.180	3.56	4.57				
	LD	.018	.022	0.46	0.56				
(DO-35)	LL	1.000	1.500	25.40	38.10				
1N4531	BD	.050	.075	1.27	1.90				
	BL	.080.	.120	2.03	3.05				
(DO-34)	LD	.018	.022	0.46	0.56				
	LL	1.000	1.500	25.40	38.10				

NOTES:

1. Dimensions are in inches. Millimeters are given for general information only.

2. In accordance with ASME Y14.5M, diameters are equivalent to Φx symbology.

TYPES 1N4148-1, 1N914, AND 1N4531.

FIGURE 1. Physical dimensions (DO-34 and DO-35).

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